| Maxim's $\mathrm{HI}-201 \mathrm{HS}$ is a monolithic, CMOS, quad, single-pole-single-throw (SPST), high-speed analog switch featuring fast switching times (toff, toN $\leq 50 \mathrm{~ns}$ ) and low on resistance ( $50 \Omega$ max). It is pin compatible with the industry-standard DG201A. <br> Maxim's new high-voltage silicon-gate technology increases the maximum supply-voltage rating to 44 V . This improvement allows continuous operation with $\pm 20 \mathrm{~V}$ supplies, which is not permitted with the original manufacturer's devices. Maxim's HI-201HS operates from dual supplies ranging from $\pm 5 \mathrm{~V}$ to $\pm 20 \mathrm{~V}$, or from single supplies from +12 V to +20 V . Logic levels are TL-/CMOS-compatible with single or dual supplies within these ranges. <br> Maxim's HI-201HS is guaranteed not to latch up if power supplies are disconnected while the analog-switch inputs are present, provided the switch continuous-current ratings are not exceeded. When powered up, the HI-201HS will switch analog signals up to the power-supply rails. $\qquad$ Applications <br> Automatic Test Equipment (ATE) <br> Heads-Up Displays <br> Communication Systems <br> Sample-and-Hold Cirçuits <br> Military |
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## —__ Foatures

Guarmiteed Singlo-Supply Operation: +12 V to +20 V

- Guarambed Dual Supplies: $\pm 5 \mathrm{~V}$ to $\pm 20 \mathrm{~V}$

Fast Switching Times:
ton $=30 \mathrm{~ns}$
toff $=40 \mathrm{~ns}$
Low, $50 \Omega$ Max On Resistance
TTL-ICMOS-Compatible
44V Max Supply Rating

| Ordering Information |  |  |
| :---: | :---: | :---: |
| PART | temp. Range | PIN-PACKAGE |
| H13-0201HS-5 | $0^{\circ} \mathrm{C}$ to $+70^{\circ} \mathrm{C}$ | 16 Plastic DIP |
| H16-0201HS-5 | $0^{\circ} \mathrm{C}$ to $+70^{\circ} \mathrm{C}$ | 16 Narrow SO |
| H11-0201HS-5 | $0^{\circ} \mathrm{C}$ to $+70^{\circ} \mathrm{C}$ | 16 CERDIP |
| H10-0201HS-6 | $0^{\circ} \mathrm{C}$ to $+70^{\circ} \mathrm{C}$ | Dice* |
| H13-0201HS-9 | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | 16 Plastic DIP |
| H16-0201HS-9 | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | 16 Narrow SO |
| H11-0201HS-9 | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | 16 CERDIP |
| H17-0201HS-2 | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | 16 CERDIP |
| H14-0201HS-8 | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | $20 \mathrm{LCC}^{* *}$ |



MAXIM
Maxim Intagrated Products

## High-Speed, CMOS, Quad, SPST Analog Switch

## ABSOLUTE MAXIMUM RATINGS

| $V_{+} \ldots \ldots \ldots \ldots . . . . . . .$. |
| :---: |
|  |  |

GND $\ldots \ldots 25$ Digital Inputs $V_{S}$, $V_{D}$ (Note 1$) \ldots(V--4 V)$ to $(V++4 V)$ or 30 mA Current (any terminal, except S or D) ................. 30 mA Continuous Current, S or D ............................. 20 mA Peak Current, Sor D (pulsed at $1 \mathrm{~ms}, 10 \%$ duty cycle max) ............... 40 mA

Continuous Power Dissipation ( $\mathrm{TA}=+70^{\circ} \mathrm{C}$, Note 2) 16-Pin DIP (derate $10.53 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ above $+70^{\circ} \mathrm{C}$ ).
16 -Pin Wide SO (derate $9.52 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ above $+70^{\circ} \mathrm{C}$ 16 -Pin Wide SO (derate $9.52 \mathrm{~m} W^{\circ}$ above $+700^{\circ} \ldots 762 \mathrm{~mW}$ $20-$ Pin LCC (derate $9.09 \mathrm{~mW} / /^{\circ} \mathrm{C}$ above $+70^{\circ} \mathrm{C}$ ) $\ldots 800 \mathrm{~mW}$ Operating Temperature Ranges: HI-0201HS-5/-6 HI-0201HS-5/-6
H1-0201HS-9. HI-0201HS-2/-8 Storage Temperature Rang
$1 . .$.
$\cdots \cdots,-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ Lead Temperature (soldering, 10 coc ) $\quad-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C},+300^{\circ} \mathrm{C}$

Note 1: Signals on Sx , Dx , or INx exceeding $\mathrm{V}+$ or V - are clamped by internal diodes. Limit forward current to maximum curren Note 2: All leads soldered or welded to PC board

Stresses beyond those iisted under "Absolute Maximum Ratings" may cause permanent damage to the device These are stress ratings only, and functional
operation of the device at these or any other condifions beyond those indicated in the operational sections of the specifications is not implied Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## ELECTRICAL CHARACTERISTICS

| PARAMETER | SYMBOL | CONDITIONS |  | H1-201HS-2/-8 |  |  | HI-201HS-5/-6/-9 |  |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | $\begin{array}{\|c} \text { MIN } \\ \text { (Note 3) } \end{array}$ | $\begin{aligned} & \text { TYP } \\ & \text { (Note 4) } \end{aligned}$ | Max | $\begin{gathered} \text { MIN } \\ \text { (Note 3) } \end{gathered}$ | $\underset{\text { (Note 4) }}{\text { TYP }}$ | max |  |
| SWITCH |  |  |  |  |  |  |  |  |  |  |
| Analog-Signal Range | VANALOG |  |  | -15 |  | 15 | -15 |  | 15 | V |
| Drain-Source On Resistance (Note 5) | 'os (on) | $V_{D}= \pm 10 \mathrm{~V}$, | $\mathrm{IN}=0.8 \mathrm{~V}, \mathrm{Is}=1 \mathrm{~mA}$ |  | 30 | 50 |  | 30 | 50 | $\Omega$ |
| Source-Off Leakage Current | Is (off) | $\mathrm{V}_{1 \mathrm{~N}}=3.0 \mathrm{~V}$ | $V_{S}=14 \mathrm{~V}, V_{D}=-14 \mathrm{~V}$ | -1 | $\pm 0.01$ | 1 | -1 | $\pm 0.01$ | 1 | nA |
|  |  |  | $V_{S}=-14 \mathrm{~V}, V_{D}=14 \mathrm{~V}$ | -1 | $\pm 0.02$ | 1 | -1 | $\pm 0.02$ | 1 |  |
| Drain-Off Leakage Current | 10 (oft) | $\mathrm{VIN}=3.0 \mathrm{~V}$ | $V_{D}=14 \mathrm{~V}, V_{S}=-14 \mathrm{~V}$ | -1 | $\pm 0.01$ | 1 | -1 | $\pm 0.01$ | 1 | nA |
|  |  |  | $V_{D}=-14 \mathrm{~V}, V_{S}=14 \mathrm{~V}$ | -1 | $\pm 0.02$ | 1 | -1 | $\pm 0.02$ | 1 |  |
| Drain-On Leakage Current (Note 6) | ID (on) | $V_{D}=-14 \mathrm{~V}, V_{\mathbb{N}}=0.8 \mathrm{~V}$ |  | -1 | $\pm 0.10$ | 1 | -1 | $\pm 0.10$ | 1 | nA |
|  |  | $\mathrm{V}_{\mathrm{D}}=14 \mathrm{~V}, \mathrm{~V}_{\mathrm{IN}}=0.8 \mathrm{~V}$ |  | -1 | $\pm 0.15$ | 1 | -1 | $\pm 0.15$ | 1 |  |
| LOGIC INPUT |  |  |  |  |  |  |  |  |  |  |
| Input Current with Input Voltage High | IINH | $\mathrm{V} / \mathrm{N}=3.0 \mathrm{~V}$ |  | -1 | 0 | 1 | -1 | 0 | 1 | $\mu \mathrm{A}$ |
|  |  | V IN $=15 \mathrm{~V}$ |  | -1 | 0 | 1 | -1 | 0 | 1 |  |
| Input Current with Input Voltage Low | IINL | $V_{I N}=0.8 V$ |  | -1 | 0 | 1 | -1 | 0 | 1 | $\mu \mathrm{A}$ |



## High-Speed, CMOS, Quad, SPST Analog Switch

| ELECTRICAL CHARACTERISTICS (continued) <br> $\left(\mathrm{V}+=15 \mathrm{~V}, \mathrm{~V}-=-15 \mathrm{~V}, \mathrm{GND}=0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}\right.$, unless otherwise noted.) |  |  |  |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| PARAMETER | SYMBOL | CONDITIONS |  | H1-201HS-2-8 |  |  | HI-201HS-5/-6/-9 |  |  | UNITS |
|  |  |  |  | $\underset{(\text { Note 3) }}{\text { MIN }}$ | $\begin{aligned} & \text { TYP } \\ & \text { (Note 4) } \end{aligned}$ | MAX | $\begin{gathered} \text { MIN } \\ \text { (Note 3) } \end{gathered}$ | $\begin{aligned} & \text { TYP } \\ & \text { (Note 4) } \end{aligned}$ | MAX |  |
| DYNAMIC |  |  |  |  |  |  |  |  |  |  |
| Turn-On Time | ton | Figure 6 |  |  | 30 | 50 |  | 30 | 50 | ns |
| Turn-Off Time | toff | Figure 6 |  |  | 40 | 50 |  | '40 | 50 | ns |
|  | toff2 |  |  |  | 150 |  |  | 150 |  |  |
| Output Settling Time |  |  |  |  | 180 |  |  | 180 |  | ns |
| Charge Injection | Q | $C_{L}=1000 p F, V_{G E N}=0 V$, Rgen $=0 \Omega$ |  |  | 10 |  |  | 10 |  | pC |
| Source-Off Capacitance | Cs (oft) | $\mathrm{V}_{S}=0 \mathrm{~V}, \mathrm{~V}_{1} \mathrm{~N}=5 \mathrm{~V}$ | $\mathrm{f}=140 \mathrm{kHz}$ |  | 10 |  |  | 10 |  | pF |
| Drain-Off Capacitance | $\mathrm{CD}_{\mathrm{D} \text { (off) }}$ | $V_{S}=0 \mathrm{~V}, \mathrm{~V}_{1}=5 \mathrm{~V}$ | $\mathrm{f}=140 \mathrm{kHz}$ |  | 10 |  |  | 10 |  | pF |
| Channel-On Capacitance | $\begin{aligned} & {\mathrm{CD}(\mathrm{on})^{+}}^{\mathrm{CS}(\mathrm{n})} \\ & \hline \end{aligned}$ | $V_{D}=V_{S}=O V, V / N=O V$ | $\mathrm{f}=140 \mathrm{kHz}$ |  | 30 |  |  | 30 |  | pF |
| Off Isolation |  | $V_{I N}=3 V_{\text {RMS }}, Z 2=1 \mathrm{k} \Omega, f=100 \mathrm{kHz}$ |  |  | 72 |  |  | 72 |  | dB |
| Crosstalk <br> (Channel-to-Channel) |  | $V_{S}=2.0 \mathrm{~V}, \mathrm{f}=100 \mathrm{kHz}$ |  |  | 90 |  |  | 90 |  | dB |
| SUPPLY |  |  |  |  |  |  |  |  |  |  |
| Positive Supply Current | $1+$ | All channels on or off |  | -3.0 | 3.8 | 6.5 | -3.0 | 3.8 | 6.5 | mA |
| Negative Supply Current | \|- |  |  |  | 1.0 |  |  | 1.0 |  | mA |
| Power-Supply Range for Continuous Operation | Vop | (Note 5) |  | $\pm 4.5$ |  | $\pm 20$ | $\pm 4.5$ |  | $\pm 20$ | V |

## High-Speed, CMOS, Quad, SPST Analog Switch

## SHLOZ-IH

ELECTRICAL CHARACTERIStICS
$\left(\mathrm{V}+=15 \mathrm{~V}, \mathrm{~V}-=-15 \mathrm{~V}, \mathrm{GND}=0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=\mathrm{T}_{\mathrm{MIN}}\right.$ to $\mathrm{T}_{\mathrm{MAX}}$, unless otherwise noted.


## High-Speed, CMOS, Quad, SPST Analog Switch

## Protecting Against

 Fault ConditionsFault conditions occur when power supplies are turned off and input signals are still present, or when overvol tages occur at the inputs during normal operation. In either case, source-to-body diodes can be forward biased and conduct current from the signal source. If this current must be kept at low ( $\mu \mathrm{A}$ ) levels, we recommend adding external protection diodes (Figure 1).

To provide protection for overvoltages up to 20 V above the supplies, place a 1 N4001 or 1N914 type diode in series with the positive and negative supplies, as show in Figure 1. Adding these diodes will reduce the analog signal range to 1 V below the positive supply and 1 V above the negative supply


Figure 2. On Resistance


Figure 3. On Leakage Current


Figure 4. Off Leakage Current

## High-Speed, CMOS, Quad, SPST Analog Switch



## High-Speed, CMOS, Quad, SPST Analog Switch



High-Speed, CMOS, Quad, SPST Analog Switch


